

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LCX244F, TC74LCX244FW, TC74LCX244FT**LOW VOLTAGE OCTAL BUS BUFFER
WITH 5V TOLERANT INPUTS AND OUTPUTS**

The TC74LCX244 is a high performance CMOS OCTAL BUS BUFFER. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for both inputs and outputs.

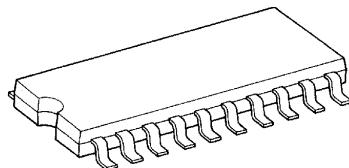
The 74LCX244 is a non-inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc. All inputs are equipped with protection circuits against static discharge.

FEATURES

- Low voltage operation : $V_{CC} = 2.0 \sim 3.6V$
- High speed operation : $t_{pd} = 6.5ns$ (Max.)
($V_{CC} = 3.0 \sim 3.6V$)
- Output current : $|I_{OH}| / |I_{OL}| = 24mA$ (Min.)
($V_{CC} = 3.0V$)
- Latch-up performance : $\pm 500mA$
- Available in JEDEC SOP, EIAJ SOP and TSSOP
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series
(74AC/VHC/HC/F/ALS/LS etc.) 244 type.

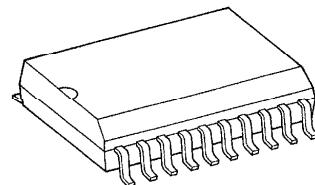
(Note) The JEDEC SOP (FW) is not available in Japan.

TC74LCX244F



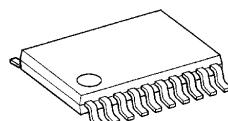
SOP20-P-300-1.27

TC74LCX244FW



SOL20-P-300-1.27

TC74LCX244FT



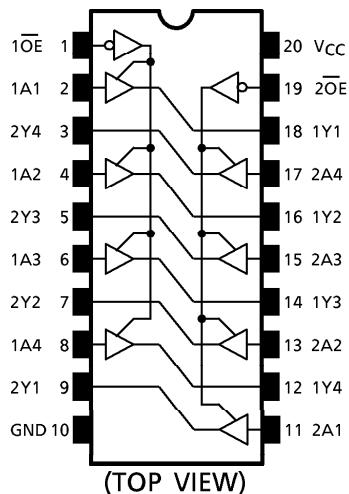
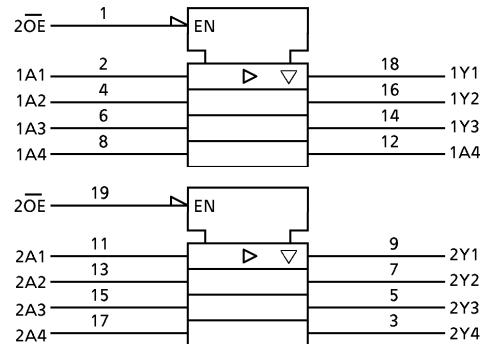
TSSOP20-P-0044-0.65

Weight

SOP20-P-300-1.27	: 0.22g (Typ.)
SOL20-P-300-1.27	: 0.46g (Typ.)
TSSOP20-P-0044-0.65	: 0.08g (Typ.)

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- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

PIN ASSIGNMENT**IEC LOGIC SYMBOL****TRUTH TABLE**

INPUTS		OUTPUTS
OE	An	
L	L	L
L	H	H
H	X	Z

X : Don't Care

Z : High Impedance

MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V _{CC}	-0.5~7.0	V
DC Input Voltage	V _{IN}	-0.5~7.0	V
DC Output Voltage	V _{OUT}	-0.5~7.0 (Note 1)	V
		-0.5~V _{CC} + 0.5 (Note 2)	
Input Diode Current	I _{IK}	-50	mA
Output Diode Current	I _{OK}	± 50 (Note 3)	mA
DC Output Current	I _{OUT}	± 50	mA
Power Dissipation	P _D	180	mW
DC V _{CC} /Ground Current	I _{CC} /I _{GND}	± 100	mA
Storage Temperature	T _{stg}	-65~150	°C

(Note 1) Output in Off-State

(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.(Note 3) V_{OUT}<GND, V_{OUT}>V_{CC}

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- The information contained herein is subject to change without notice.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
		1.5~3.6 (Note 4)	
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	± 24 (Note 7)	mA
		± 12 (Note 8)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns/V

(Note 4) Data Retention Only

(Note 5) Output in Off-State

(Note 6) High or Low State

(Note 7) $V_{CC} = 3.0 \sim 3.6V$ (Note 8) $V_{CC} = 2.7 \sim 3.0V$ (Note 9) $V_{IN} = 0.8 \sim 2.0V$, $V_{CC} = 3.0V$

ELECTRICAL CHARACTERISTICS

DC characteristics ($T_a = -40 \sim 85^\circ C$)

PARAMETER		SYMBOL	TEST CONDITION	V_{CC} (V)	MIN.	MAX.	UNIT	
Input Voltage	"H" Level	V_{IH}		2.7~3.6	2.0	—	V	
	"L" Level	V_{IL}		2.7~3.6	—	0.8		
Output Voltage	"H" Level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100\mu A$	2.7~3.6	$V_{CC} - 0.2$	V	
				$I_{OH} = -12mA$	2.7	2.2		
				$I_{OH} = -18mA$	3.0	2.4		
				$I_{OH} = -24mA$	3.0	2.2		
	"L" Level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100\mu A$	2.7~3.6	—	V	
				$I_{OL} = 12mA$	2.7	—		
				$I_{OL} = 16mA$	3.0	—		
				$I_{OL} = 24mA$	3.0	—		
Input Leakage Current	I_{IN}	$V_{IN} = 0 \sim 5.5V$		2.7~3.6	—	± 5.0	μA	
3-State Output Off-State Current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0 \sim 5.5V$		2.7~3.6	—	± 5.0	μA	
Power Off Leakage Current	I_{OFF}	$V_{IN} / V_{OUT} = 5.5V$		0	—	10.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		2.7~3.6	—	10.0	μA	
		$V_{IN} / V_{OUT} = 3.6 \sim 5.5V$		2.7~3.6	—	± 10.0		
Increase In I_{CC} Per Input	ΔI_{CC}	$V_{IH} = V_{CC} - 0.6V$		2.7~3.6	—	500	μA	

AC characteristic ($T_a = -40\sim85^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	MIN.	MAX.	UNIT
Propagation Delay Time	t_{pLH}	(Fig.1, 2)	2.7	—	7.5	ns
	t_{pHL}		3.3 ± 0.3	1.5	6.5	
Output Enable Time	t_{pZL}	(Fig.1, 3)	2.7	—	9.0	ns
	t_{pZH}		3.3 ± 0.3	1.5	8.0	
Output Disable Time	t_{pLZ}	(Fig.1, 3)	2.7	—	8.0	ns
	t_{pHZ}		3.3 ± 0.3	1.5	7.0	
Output To Output Skew	t_{osLH}	(Note 10)	2.7	—	—	ns
	t_{osHL}		3.3 ± 0.3	—	1.0	

(Note 10) Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

DYNAMIC SWITCHING CHARACTERISTICS ($T_a = 25^\circ C$, Input $t_r = t_f = 2.5\text{ns}$, $C_L = 50\text{pF}$, $R_L = 500\Omega$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	TYP.	UNIT
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$	3.3	0.8	V
Quiet Output Minimum Dynamic V_{OL}	$ V_{OLV} $	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$	3.3	0.8	V

CAPACITIVE CHARACTERISTICS ($T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	TYP.	UNIT	
Input Capacitance	C_{IN}	—	3.3	7	pF	
Output Capacitance	C_{OUT}		3.3	8	pF	
Power Dissipation Capacitance	C_{PD}	$f_{IN} = 10\text{MHz}$	(Note 11)	3.3	25	pF

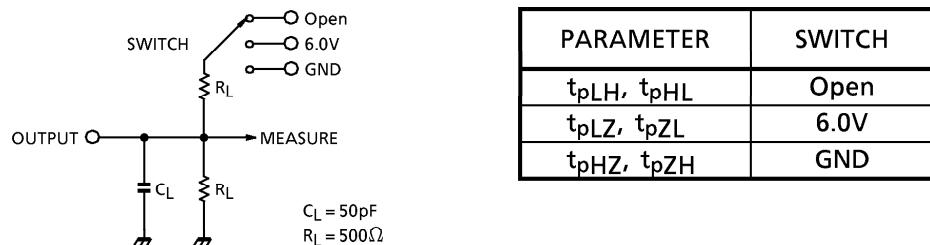
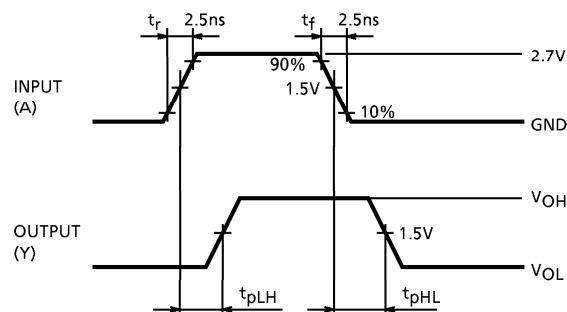
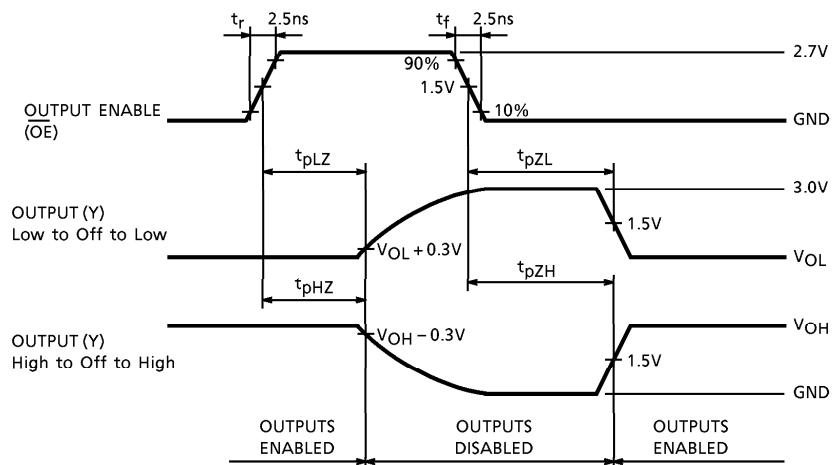
(Note 11) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

TEST CIRCUIT

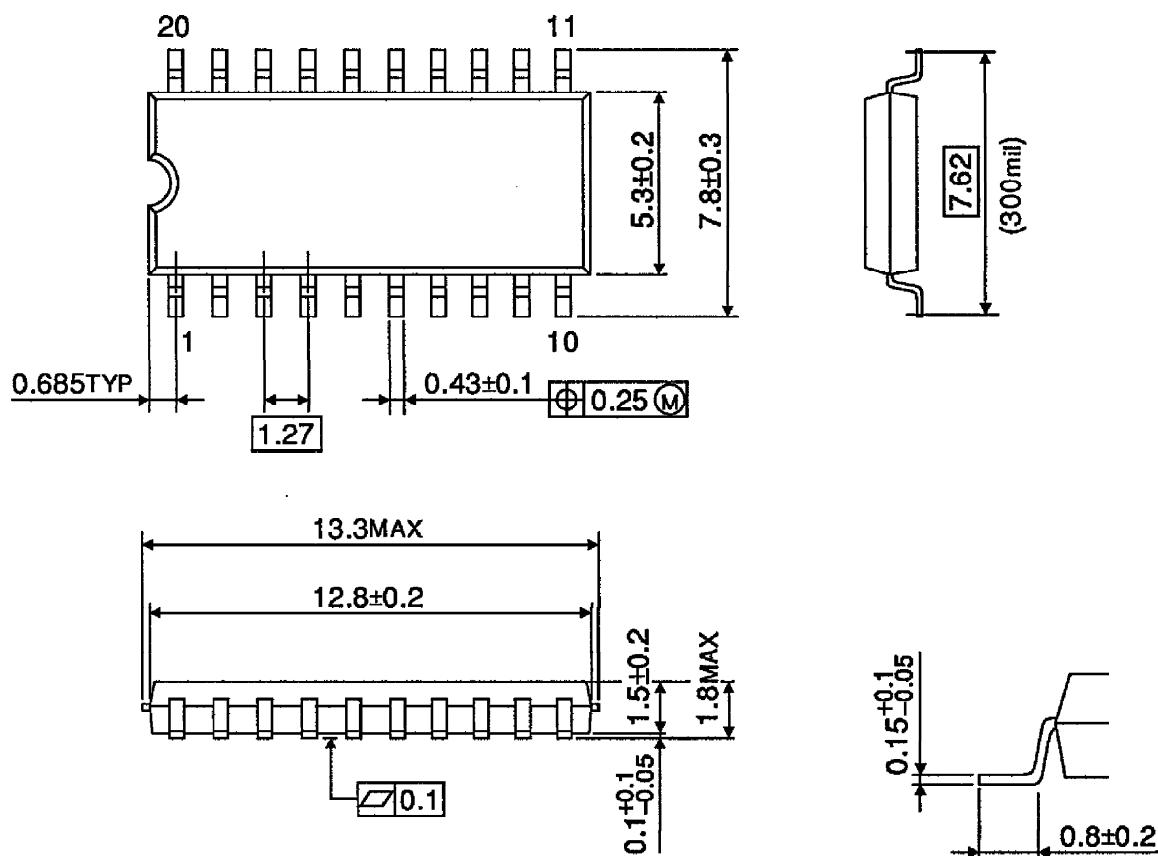
Fig.1

**AC WAVEFORM**Fig.2 t_{pLH}, t_{pHL} Fig.3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

OUTLINE DRAWING

SOP20-P-300-1.27

Unit : mm



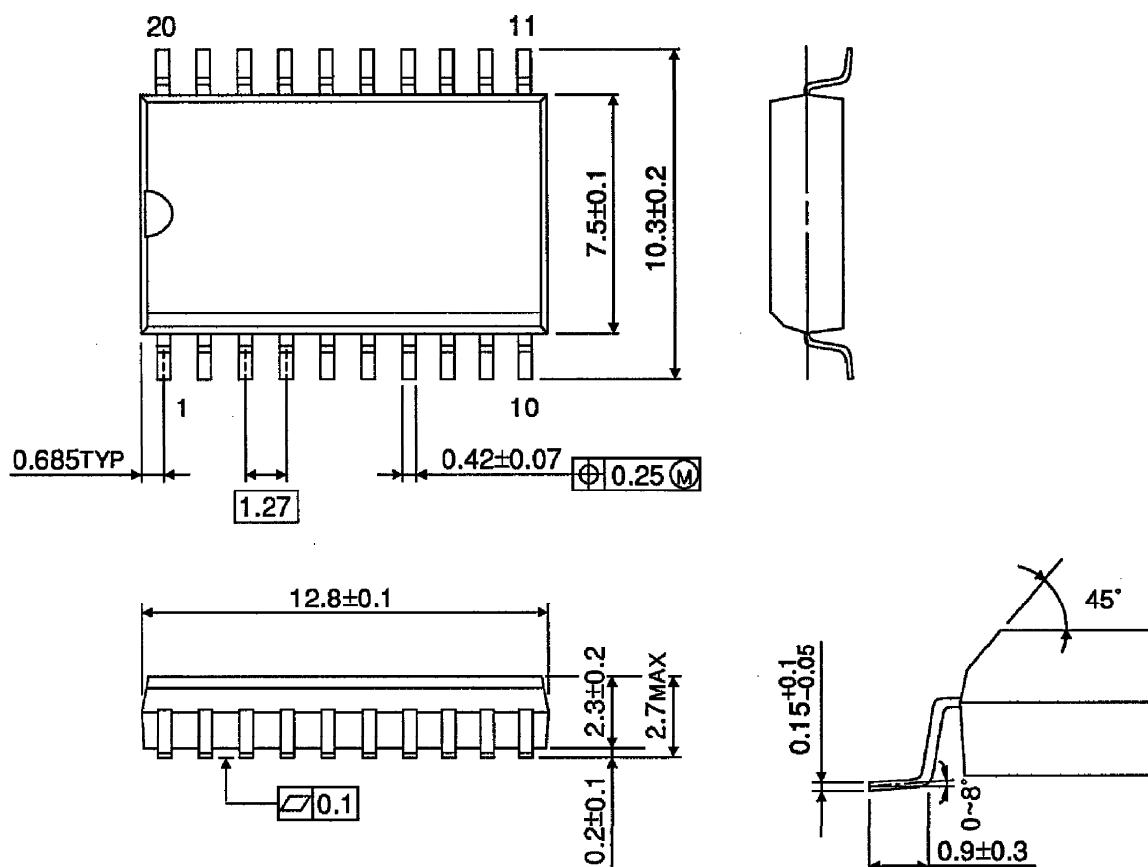
Weight : 0.22g (Typ.)

OUTLINE DRAWING

SOL20-P-300-1.27

Unit : mm

(Note) This package is not available in Japan.

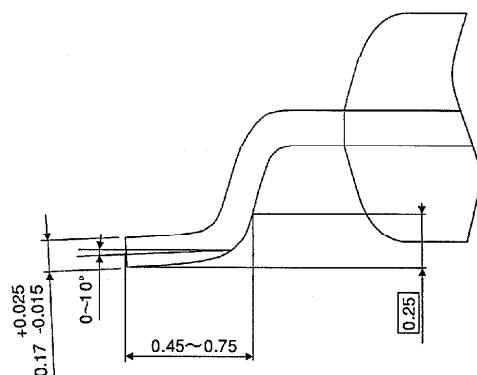
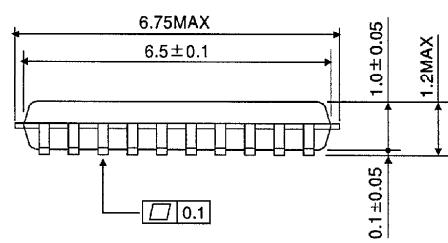
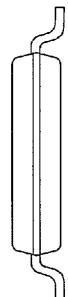
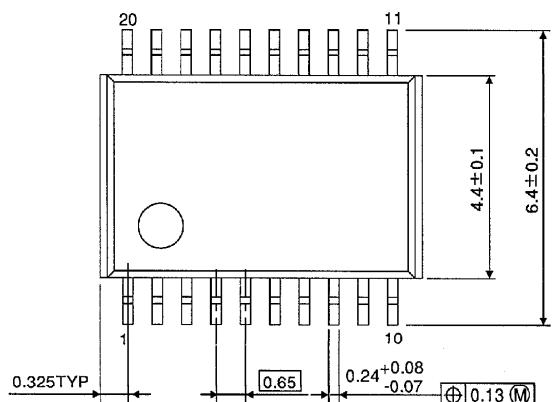


Weight : 0.46g (Typ.)

OUTLINE DRAWING

TSSOP20-P-0044-0.65

Unit : mm



Weight : 0.08g (Typ.)